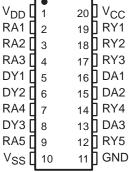
SLLS065F - AUGUST 1989 - REVISED JANUARY 2000

- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU Recommendation
- Single Chip With Easy Interface Between **UART and Serial-Port Connector**
- **Less Than 9-mW Power Consumption**
- Wide Driver Supply Voltage . . . 4.5 V to 13.2 V
- **Driver Output Slew Rate Limited to** 30 V/us Max
- Receiver Input Hysteresis . . . 1100 mV Typ
- **Push-Pull Receiver Outputs**
- On-Chip Receiver 1-us Noise Filter
- **Functionally Interchangeable With Texas** Instruments SN75185
- Operates Up to 120 kbit/s Over a 3-Meter Cable (See Application Information for Conditions)

DW OR N PACKAGE (TOP VIEW)



description

The SN75C185 is a low-power BiMOS device containing three independent drivers and five receivers that are used to interface data terminal equipment (DTE) with data circuit-terminating equipment (DCE). Typically, the SN75C185 replaces one SN75188 and two SN75189 devices. This device conforms to TIA/EIA-232-F. The drivers and receivers of the SN75C185 are similar to those of the SN75C188 and SN75C189A, respectively. The drivers have a controlled output slew rate that is limited to a maximum of 30 V/µs, and the receivers have filters that reject input noise pulses that are shorter than 1 µs. Both these features eliminate the need for external components.

The SN75C185 uses the low-power BiMOS technology. In most applications, the receivers contained in this device interface to single inputs of peripheral devices such as ACEs, UARTS, or microprocessors. By using sampling, such peripheral devices usually are insensitive to the transition times of the input signals. If this is not the case, or for other uses, it is recommended that the SN75C185 receiver outputs be buffered by single Schmitt input gates or single gates of the HCMOS, ALS, or 74F logic families.

The SN75C185 is characterized for operation from 0°C to 70°C.

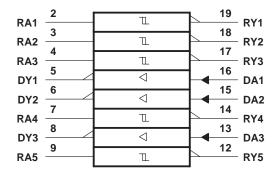


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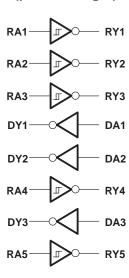
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logic symbol†



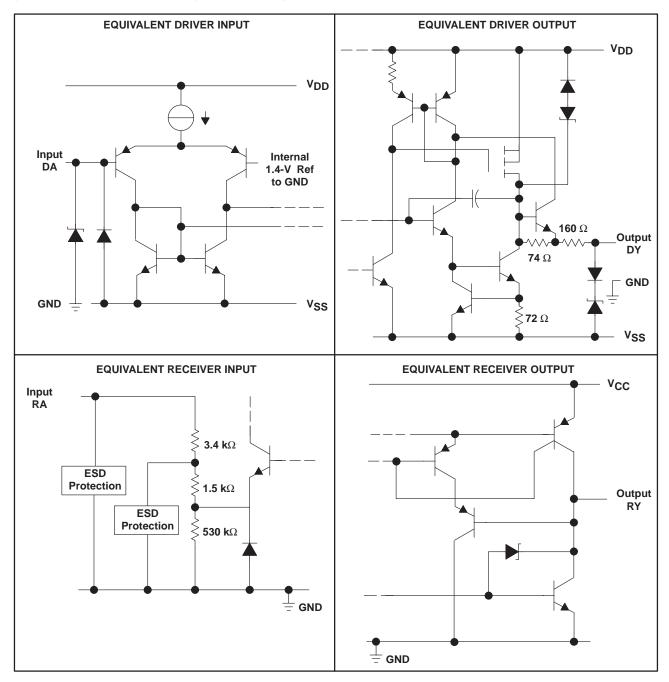
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





equivalent schematics of inputs and outputs



All resistor values are nominal.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{DD} (see Note 1)	
Supply voltage, V _{SS}	
Supply voltage, V _{CC}	7 V
Input voltage range, V _I : Driver	V _{SS} to V _{DD}
Receiver	–30 V to 30 V
Output voltage range, V _O : Driver	\dots V _{SS} -6 V to V _{DD} + 6 V
Receiver	$-0.3 \text{ V to V}_{CC} + 0.3 \text{ V}$
Package thermal impedance, θ_{JA} (see Note 2): DW package	58°C/W
N package	69°C/W
Operating free-air temperature range, T _A	0°C to 70°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T _{Stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			MIN	NOM	MAX	UNIT
		V_{DD}	4.5	12	13.2	V
	Supply voltage	V _{SS}	-4.5	-12	-13.2	V
		Vcc	4.5	5	6	V
\/.	Input valtage (see Note 2)	Drivers	V _{SS} +2		V_{DD}	V
VI	Input voltage (see Note 3)	Receivers			25	V
VIH	High-level input voltage	Drivers	2			V
V _{IL}	Low-level input voltage	Drivers			0.8	V
IOH	High-level output current	Receivers			-1	mA
loL	High-level output current	Receivers			3.2	mA
T _A	Operating free-air temperature		0		70	°C

NOTE 3: The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only, e.g., if -10 V is a maximum, the typical value is a more negative voltage.

supply currents

	PARAMETER	TEST	CONDITIONS	MIN	TYP	MAX	UNIT	
1	Supply current from VDD	No load,	$V_{DD} = 5 V$,	$V_{SS} = -5 V$		115	200	
'DD	зирріў сипені поні VDD	All inputs at 2 V or 0.8 V	V _{DD} = 12 V,	V _{SS} = -12 V		115	200	μΑ
laa	Cupply ourront from Voc	No load,	$V_{DD} = 5 V$,	$V_{SS} = -5 V$		-115	-200	
ISS	Supply current from VSS	All inputs at 2 V or 0.8 V	V _{DD} = 12 V,	V _{SS} = -12 V		-115	-200	μΑ
laa	Supply current from Voc	No load	$V_{DD} = 5 V$,	$V_{SS} = -5 \text{ V}$			750	μA
Icc	Supply current from V _{CC} All inputs at 0 or 5 V		V _{DD} = 12 V,	$V_{SS} = -12 \text{ V}$			750	μΑ



NOTES: 1. All voltages are with respect to network GND.

^{2.} The package thermal impedance is calculated in accordance with JESD 51.

DRIVER SECTION

electrical characteristics over operating free-air temperature range, V_{DD} = 12 V, V_{SS} = –12 V, V_{CC} = 5 V $\pm 10\%$ (unless otherwise noted)

	PARAMETER TES			ONDITIONS		MIN	TYP†	MAX	UNIT
Vou	High-level output voltage	V _{IL} = 0.8 V,	$R_L = 3 k\Omega$,	$V_{DD} = 5 V$,	$V_{SS} = -5 V$	4	4.5		V
VOH	nigri-level output voltage	See Figure 1		V _{DD} = 12 V	$V_{SS} = -12 \text{ V}$	10	10.8		V
Voi	V _{OL} Low-level output voltage (see Note 3) V _{IH} = 0.8 V, See Figure 1		$R_L = 3 k\Omega$,	$V_{DD} = 5 V$,	$V_{SS} = -5 V$		-4.4	-4	V
VOL				V _{DD} = 12 V	$V_{SS} = -12 \text{ V}$		-10.7	-10	V
lН	High-level input current	V _I = 5 V, See Figure 2					1	μΑ	
I _I L	Low-level input current	$V_{I} = 0$,	See Figure	2				-1	μΑ
IOS(H)	High-level short-circuit output current (see Note 4)	V _I = 0.8 V, See Flgure 1	$V_O = 0$ or V	o = V _{SS} ,		-4.5	-12	-19.5	mA
los(L)	Low-level short-circuit output current (see Note 4)	V _I = 2 V, See Figure 1	V _O = 0 or V	O = VDD,		4.5	12	19.5	mA
r _O	Output resistance	V _{DD} = V _{SS} = See Note 5	V _{CC} = 0,	$V_0 = -2 \text{ V to}$	2 V,	300	400	·	Ω

[†] All typical values are at $T_A = 25$ °C.

NOTES: 3. The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only, e.g., if –10 V is a maximum, the typical value is a more negative voltage.

- 4. Not more than one output should be shorted at one time.
- 5. Test conditions are those specified by TIA/EIA-232-F.

switching characteristics, V_{DD} = 12 V, V_{SS} = -12 V, V_{CC} = 5 V ±10%, T_A = 25°C (unless otherwise noted) (see Figure 3)

	PARAMETER	TEST COND	DITIONS	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output (see Note 6)				1.2	3	μs
tPHL	Propagation delay time, high- to low-level output (see Note 6)	$R_L = 3 k\Omega$ to 7 kΩ,	C _L = 15 pF		2.5	3.5	μs
tTLH	Transition time, low- to high-level output			0.53	2	3.2	μs
tTHL	Transition time, high- to low-level output			0.53	2	3.2	μs
tTLH	Transition time, low- to high-level output (see Note 7)	$R_1 = 3 k\Omega \text{ to } 7 k\Omega$	C ₁ = 2500 pF		1		μs
tTHL	Transition time, high- to low-level output (see Note 7)	K[= 3 K22 to 7 K22,	CL = 2300 pr		1		μs
SR	Output slew rate (see Note 7)	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	C _L = 15 pF	4	10	30	V/μs

NOTES: 6. tpHL and tpLH include the additional time due to on-chip slew rate and are measured at the 50% points.

7. Measured between 3-V and -3-V points of output waveform TIA/EIA-232-F conditions), and all unused inputs are tied either high or low.



RECEIVER SECTION

electrical characteristics over operating free-air temperature range, V_{DD} = 12 V, V_{SS} = -12 V, V_{CC} = 5 V $\pm 10\%$ (unless otherwise noted)

	PARAMETER		TEST COND	TIONS	MIN	TYP [†]	MAX	UNIT
V _{IT+}	Positive-going input threshhold voltage	See Figure 5			1.6	2.1	2.55	V
VIT-	Negative-going input threshhold voltage	See Figure 5			0.65	1	1.25	V
V _{hys}	Input hysteresis voltage (V _{IT+} - V _{IT-})				600	1100		mV
V _I = 0		V _I = 0.75 V,	$I_{OH} = -20 \mu A$,	See Figure 5 and Note 8	3.5			
\/a	High-level output voltage	V _I = 0.75 V,	V _{CC} = 4.5 V		2.8	4.4		V
VOH		$I_{OH} = -1 \text{ mA},$	V _{CC} = 5 V		3.8	4.9		l
		See Figure 5	V _{CC} = 5.5 V		4.3	5.4		
VOL	Low-level output voltage	V _I = 3 V,	$I_{OL} = 3.2 \text{ mA},$	See Figure 5		0.17	0.4	V
1	High-level input current	V _I = 3 V				0.55	1	mΛ
¹IH	riign-ievei input current	V _I = 25 V	3.6	4.6	8.3	mA		
1	Low lovel input current	V _I = −3 V			-0.43	-0.55	-1	mA
l L	Low-level input current	$V_{I} = -25 \text{ V}$ $-3.6 -5.0$					-8.3	IIIA
IOS(H)	Short-circuit output at high level	V _I = 0.75 V,	V _O = 0,	See Figure 4		-8	-15	mA
I _{OS(L)}	Short-circuit output at low level	$V_I = V_{CC}$	$V_O = V_{CC}$	See Figure 4		13	25	mA

[†] All typical values are at T_A = 25 °C.

NOTE 8: If the inputs are left unconnected, the receiver interprets this as an input low, and the receiver outputs remain in the high state.

switching characteristics, V_{DD} = 12 V, V_{SS} = -12 V, V_{CC} = 5 V ±10%, T_A = 25°C (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CC	MIN	TYP	MAX	UNIT	
tPLH	Propagation delay time, low- to high-level output				3	4	μs
tPHL	Propagation delay time, high- to low-level output	$R_1 = 5 k\Omega$	$C_{1} = 50 pF$		3	4	μs
tTLH	Transition time, low- to high-level output	$K_{\perp} = 5 \text{ K}_{2}$	CL = 50 pr		300	450	ns
tTHL	Transition time, high- to low-level output				100	300	ns
t _{w(N)}	Duration of longest pulse rejected as noise (see Note 9)	$R_L = 5 k\Omega$,	C _L = 50 pF	1		4	μs

NOTE 9: The receiver ignores any postive- or negative-going pulse that is less than the minimum value of $t_{W(N)}$ and accepts any positive- or negative-going pulse greater than the maximum of $t_{W(N)}$.



PARAMETER MEASUREMENT INFORMATION

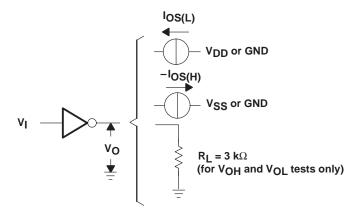


Figure 1. Driver Test Circuit for V_{OH} , V_{OL} , $I_{OS(H)}$, and $I_{OS(L)}$

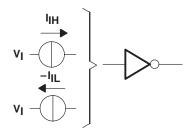
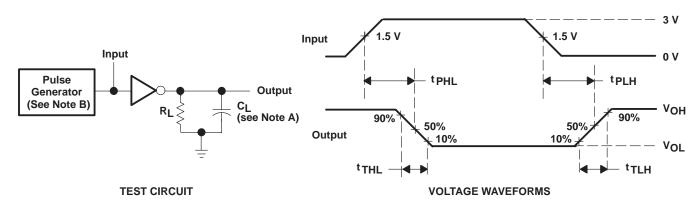


Figure 2. Driver Test Circuit for IIH and IIL



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: t_W = 25 μ s, PRR = 20 kHz, Z_O = 50 Ω , t_f = t_f < 50 ns.

Figure 3. Driver Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION

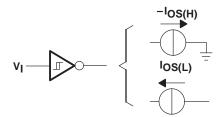


Figure 4. Receiver Test Circuit for I_{OS(H)} and I_{OS(L)}

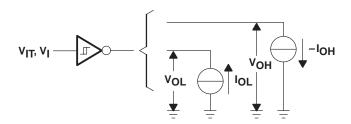
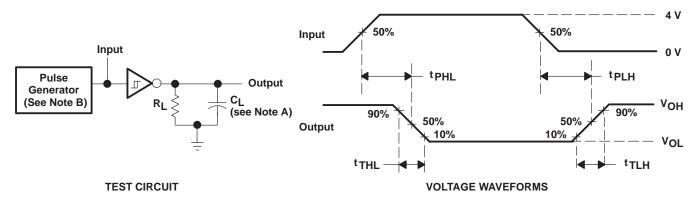


Figure 5. Receiver Test Circuit for V_{IT}, V_{OH}, and V_{OL}



- NOTES: A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: t_W = 25 μ s, PRR = 20 kHz, Z_O = 50 Ω , t_f = t_f < 50 ns.

Figure 6. Receiver Propagation and Transition Times



APPLICATION INFORMATION

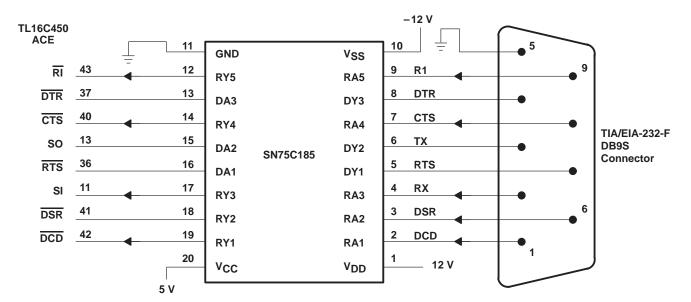
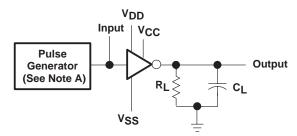


Figure 7. Typical Connection

The SN75C185 supports data rates up to 120 kbit/s over a 3-meter cable. Laboratory experiments show that, with C_L = 500 pF and R_L = 3 k Ω (minimum RS-232 input resistance load), the device can support this data rate. The 500-pF load approximates a typical 3-meter cable because the maximum RS-232 specification is 2500 pF (or about 15 meters). Figure 8 shows the test circuit used. Temperature was varied from 0°C to 70°C for the experiment.



NOTES: A. The pulse generator has the following characteristics: PRR = 60 kHz (120 kbit/s), $Z_O = 50 \Omega$.

B. $V_{CC} = 5 \text{ V}, V_{DD} = 12 \text{ V}, V_{SS} = -12 \text{ V}.$

Figure 8. Data-Rate Test Circuit





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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN75C185DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C185DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C185DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C185DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C185DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C185DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C185N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75C185NE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

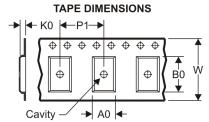
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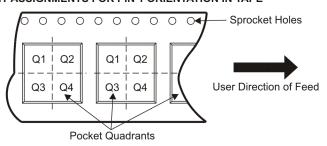
TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

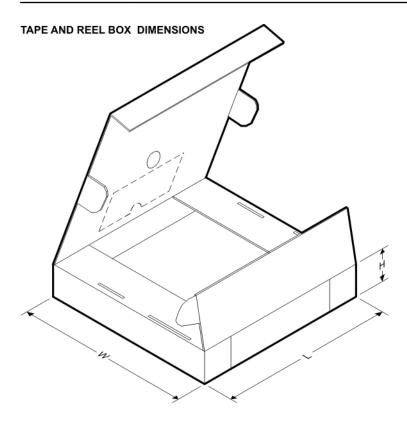
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75C185DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.1	2.65	12.0	24.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75C185DWR	SOIC	DW	20	2000	346.0	346.0	41.0

DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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